









	<h2 style="color: #E67E22;">IPD30N10S3L-34</h2>	
	Hersteller-Teilenummer:	IPD30N10S3L-34
	Hersteller / Marke:	International Rectifier (Infineon Technologies)
	Teil der Beschreibung:	IPD30N10S3L-34 Infineon Technologies
Datenblätter:	 IPD30N10S3L-34.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 20419 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	IPD30N10S3L-34
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	IPD30N10S3L-34 Infineon Technologies
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	20419 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	PG-TO252-3
Verlustleistung (max)	57W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	30A (Tc)
Rds On (Max) @ Id, Vgs	31 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.4V @ 29µA
Gate Charge (Qg) (Max) @ Vgs	31nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1976pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

IPD30N10S3L-34 ist neu im Original, Suche IPD30N10S3L-34 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPD30N10S3L-34 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPD30N10S3L-34: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IPD30N08S2L-21 International Rectifier (Infineon Technologies) IPD30N08S2L-21 Infineon Technologies</p>	 <p>IPD30N08S2L21ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 75V 30A TO252-3</p>	 <p>IPD30N12S3L31ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CHANNEL_100+</p>	 <p>IPD320N20N3 IPD320N20N3 </p>
 <p>IPD30N10S3L-34(3N10L34) INFINEO IPD30N10S3L-34(3N10L34) INFINEO</p>	 <p>IPD30N08S222ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 75V 30A TO252-3</p>	 <p>IPD320N20N3 G INFINEON IPD320N20N3 G INFINEON</p>	 <p>IPD30N10S3L34ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 100V 30A TO252-3</p>

heiße Teile

Mehr

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|------------------|------------------|---------------------|------------------|------------------|
| ⊗ IPD250N06N3G | ↔ IPD25CN10N | ⇒ IPD25CN10NG | D IPD25CNE8N | ⇒ IPD25CNE8NG |
| ⊣ IPD25N06S2-40 | ⊗ IPD25N06S4L-30 | D IPD25N06S4L-30_15 | ⇒ IPD26N06S2L-35 | ⇒ IPD30N03S2L-07 |
| ⊗ IPD30N03S2L-08 | ⊣ IPD30N03S2L-10 | ⊗ IPD30N03S2L-20 | ↔ IPD30N03S4L-09 | ⇒ IPD30N03S4L-14 |
| D IPD30N06 | ⊗ IPD30N06S2-15 | ⊣ IPD30N06S2-23 | ⊗ IPD30N06S2L-13 | ⇒ IPD30N06S2L-23 |
| ⇒ IPD30N06S3-24 | ↔ IPD30N06S3L-20 | ⊗ IPD30N06S4L-23 | ⊣ IPD30N08S2-22 | ⇒ IPD30N08S2L-21 |
| ↔ IPD320N20N3 | ⇒ IPD320N20N3G | D IPD33CN10N | ⊗ IPD33CN10NG | ⊣ IPD350N06LG |
| ⊗ IPD35CN10NG | D IPD35N10S3L-26 | ⇒ IPD400N06NG | ↔ IPD40N03S4L-08 | ⇒ IPD49CN10NG |
| ⊣ IPD50CN10NG | ⊗ IPD50N03S2-07 | ↔ IPD50N03S2L-06 | ⇒ IPD50N03S2L-07 | ⇒ IPD50N03S4L-06 |
| ⊗ IPD50N04S08 | ⊣ IPD50N04S3-08 | ⊗ IPD50N04S3-09 | D IPD50N04S4-08 | ⇒ IPD50N04S4-10 |
| ↔ IPD50N04S4L-08 | ⊗ IPD50N06L13 | ⊣ IPD50N06S2-14 | ⊗ IPD50N06S2L-13 | ⇒ IPD50N06S3-09 |

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